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NPN Transistor with Zener Diode

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NSM6056MT1G

Features

• These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- Driving Circuit
- Switching Applications

MAXIMUM RATINGS – NPN TRANSISTOR

Rating	Symbol	Value	Unit				
Collector – Emitter Voltage	V _{CEO}	40	V				
Collector – Base Voltage	V _{CBO}	60	V				
Emitter-Base Voltage	V _{EBO}	6.0	V				
Collector Current – Continuous	Ι _C	600	mA				
Collector Current – Peak	I _{CM}	900	mA				
MAXIMUM RATINGS – ZENER DIODE							

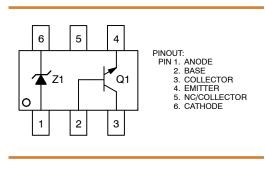
Rating	Symbol	Value	Unit	
Forward Voltage @ I _F = 10 mA	V _F	0.9	V	

THERMAL CHARACTERISTICS

Rating	Symbol	Мах	Unit	
Total Device Dissipation FR-5 Board, (Note 1) @ T _A = 25°C	PD	380	mW	
Thermal Resistance from Junction-to-Ambient	$R_{\theta JA}$	328	°C/W	
Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +150	°C	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

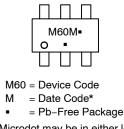
1. FR-4 Minimum Pad.







MARKING DIAGRAM



(Note: Microdot may be in either location)

*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
NSM6056MT10	G SC-74 (Pb-Free)	3000/Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

NSM6056MT1G

NPN TRANSISTOR – ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

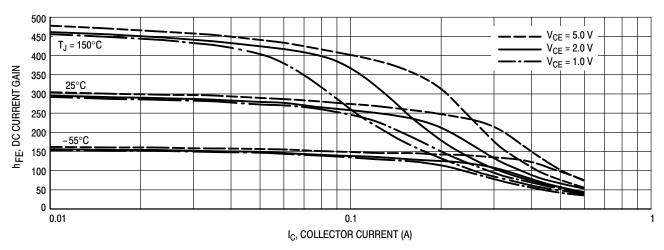
Cha	Symbol	Min	Max	Unit	
OFF CHARACTERISTICS					•
Collector – Emitter Breakdown Voltage	V _{(BR)CEO}	40	-	Vdc	
Collector – Base Breakdown Voltage	(I _C = 0.1 mAdc, I _E = 0)	V _{(BR)CBO}	60	-	Vdc
Emitter-Base Breakdown Voltage	(I _E = 0.1 mAdc, I _C = 0)	V _{(BR)EBO}	6.0	-	Vdc
Base Cutoff Current	(V _{CE} = 35 Vdc, V _{EB} = 0.4 Vdc)	I _{BEV}	-	0.1	μAdc
Collector Cutoff Current	(V _{CE} = 35 Vdc, V _{EB} = 0.4 Vdc)	I _{CEX}	-	0.1	μAdc
ON CHARACTERISTICS (Note 3)					
DC Current Gain		h _{FE}	20 40 80 100 40	- - 300 -	_
Collector – Emitter Saturation Voltage	V _{CE(sat)}		0.4 0.75	Vdc	
Base – Emitter Saturation Voltage	(I _C = 150 mAdc, I _B = 15 mAdc) (I _C = 500 mAdc, I _B = 50 mAdc)	V _{BE(sat)}	0.75	0.95 1.2	Vdc
SMALL-SIGNAL CHARACTERISTIC	S				
Current-Gain - Bandwidth Product	(I _C = 20 mAdc, V_{CE} = 10 Vdc, f = 100 MHz)	f _T	250	-	MHz
Collector-Base Capacitance	$(V_{CB} = 5.0 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz})$	C _{cb}	-	6.5	pF
Emitter-Base Capacitance	$(V_{EB} = 0.5 \text{ Vdc}, I_C = 0, f = 1.0 \text{ MHz})$	C _{eb}	-	30	pF
Input Impedance	$(I_{C} = 1.0 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz})$	h _{ie}	1.0	15	kΩ
Voltage Feedback Ratio	$(I_{C} = 1.0 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz})$	h _{re}	0.1	8.0	X 10 ⁻⁴
Small – Signal Current Gain	$(I_{C} = 1.0 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz})$	h _{fe}	40	500	-
Output Admittance	$(I_{C} = 1.0 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz})$	h _{oe}	1.0	30	μmhos
SWITCHING CHARACTERISTICS					
Delay Time	(V _{CC} = 30 Vdc, V _{EB} = 2.0 Vdc,	t _d	-	15	
Rise Time	$I_{\rm C} = 150 \text{ mAdc}, I_{\rm B1} = 15 \text{ mAdc})$	t _r	-	20	ns
Storage Time	(V _{CC} = 30 Vdc, I _C = 150 mAdc,	t _s	-	225	
Fall Time				30	ns

ZENER DIODE – ELECTRICAL CHARACTERISTICS (V_F = 0.9 Max @ I_F = 10 mA for all types)

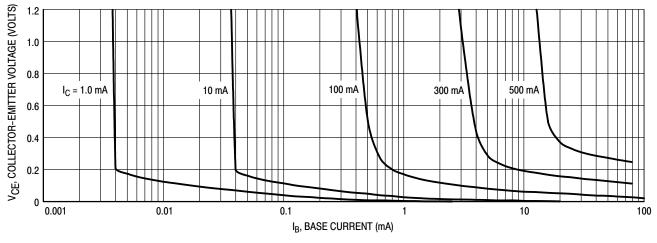
	Test	Zener Vo	ltage VZ	Z _{ZK} I _Z = 0.5		Max IR @ VR		d _{VZ} /dt (mV/k) @ I _{ZT1} = 5 mA		C pF Max @
Device	Current Izt mA	Min	Max	mA Ω Max	Mod Ω Max	μΑ	v	Min	Max	V _R = 0 f = 1 MHz
NSM6056MT1G	5.0	5.49	5.73	200	40	1.0	2.0	-2.0	2.5	200

NSM6056MT1G

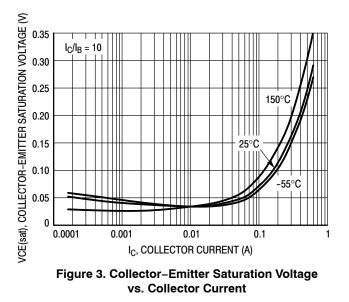
TYPICAL ELECTRICAL CHARACTERISTICS – NPN TRANSISTOR





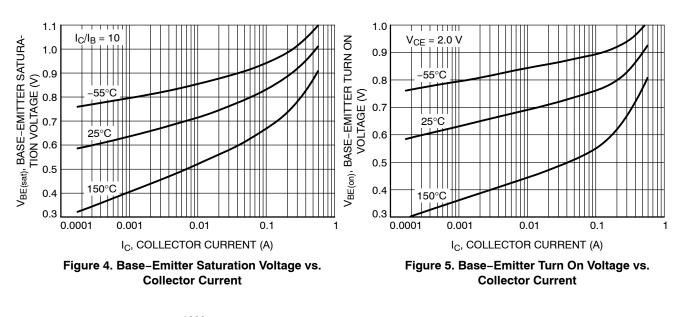


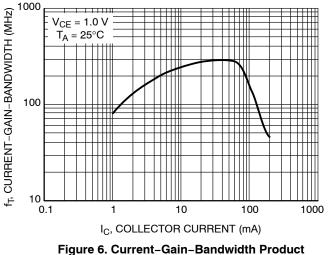




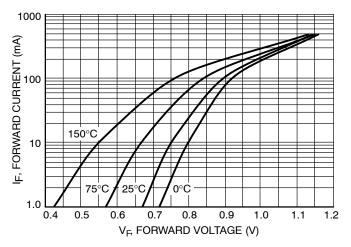
NSM6056MT1G







TYPICAL ELECTRICAL CHARACTERISTICS – ZENER DIODE

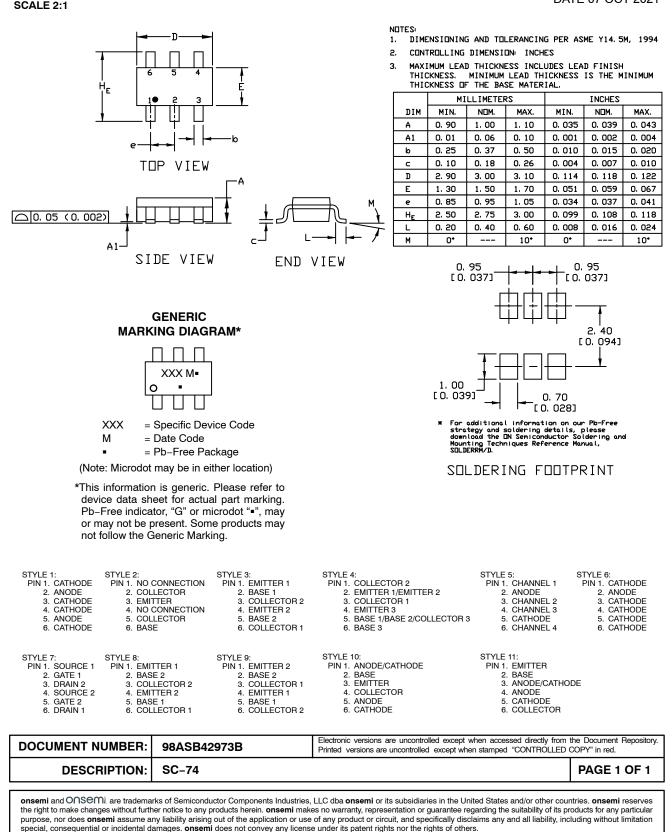




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